## The RF Line

# **NPN Silicon RF Power Transistors**

Designed for 24 volt UHF large-signal, common-emitter amplifier applications in industrial and commercial FM equipment operating in the range of 800-960 MHz.

- Specified 24 Volt, 900 MHz Characteristics Output Power = 5.0 Watts
  - Power Gain = 9.0 dB Min Efficiency = 50% Min
- Series Equivalent Large-Signal Characterization
- Capable of Withstanding 20:1 VSWR Load Mismatch at Rated Output Power and Supply Voltage
- Gold Metallized, Emitter Ballasted for Long Life and Resistance to Metal Migration
- Silicon Nitride Passivated
- Circuit board photomaster available upon request by contacting RF Tactical Marketing in Phoenix, AZ.

### **MRF891S**

5.0 W, 900 MHz RF POWER TRANSISTORS NPN SILICON



**CASE 319A-02, STYLE 2** 

#### **MAXIMUM RATINGS**

Rating	Symbol	Value	Unit
Collector–Emitter Voltage	VCEO	30	Vdc
Collector–Emitter Voltage	VCES	55	Vdc
Emitter-Base Voltage	V <sub>EBO</sub>	4.0	Vdc
Collector Current — Continuous	IC	0.6	Adc
Total Device Dissipation @ T <sub>A</sub> = 50°C (1) Derate above 50°C	P <sub>D</sub>	18 0.143	Watts W/°C
Storage Temperature Range	T <sub>stg</sub>	-65 to +150	°C

#### THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction to Case (2)	$R_{\theta JC}$	7.0	°C/W

#### **ELECTRICAL CHARACTERISTICS** ( $T_C = 25^{\circ}C$ unless otherwise noted)

Characteristic	Symbol	Min	Тур	Max	Unit	
OFF CHARACTERISTICS						
Collector–Emitter Breakdown Voltage (I <sub>C</sub> = 20 mAdc, I <sub>B</sub> = 0)	V(BR)CEO	30	_	_	Vdc	
Collector–Emitter Breakdown Voltage (I <sub>C</sub> = 20 mAdc, V <sub>BE</sub> = 0)	V(BR)CES	55	_	_	Vdc	
Emitter–Base Breakdown Voltage (I <sub>E</sub> = 0.5 mAdc, I <sub>C</sub> = 0)	V(BR)EBO	4.0	_	_	Vdc	
Collector Cutoff Current (V <sub>CE</sub> = 30 Vdc, V <sub>BE</sub> = 0, T <sub>C</sub> = 25°C)	ICES	_	_	1.0	mAdc	
ON CHARACTERISTICS						
DC Current Gain (I <sub>C</sub> = 200 mAdc, V <sub>CF</sub> = 5.0 Vdc)	hFE	30	_	150	_	

#### NOTES:

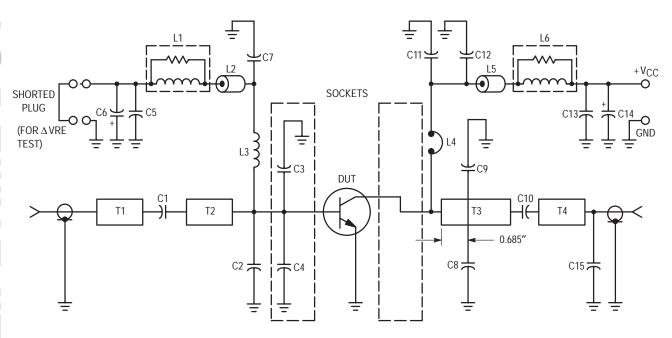
- 1. This device is designed for RF operation. The total device dissipation rating applies only when the device is operated as an RF amplifier.
- 2. Thermal Resistance is determined under specified RF operating conditions by infrared measurement techniques.

#### REV 7



#### **ELECTRICAL CHARACTERISTICS** — **continued** ( $T_C = 25^{\circ}C$ unless otherwise noted.)

Characteristic	Symbol	Min	Тур	Max	Unit
DYNAMIC CHARACTERISTICS					
Output Capacitance (V <sub>CB</sub> = 24 Vdc, I <sub>E</sub> = 0, f = 1.0 MHz)	C <sub>ob</sub>	_	6.5	8.0	pF
FUNCTIONAL TESTS					
Common–Emitter Amplifier Power Gain (Broadband) (V <sub>CC</sub> = 24 Vdc, P <sub>out</sub> = 5.0 W, f = 900 MHz)	G <sub>pe</sub>	9.0	10	_	dB
Collector Efficiency (V <sub>CC</sub> = 24 Vdc, P <sub>out</sub> = 5.0 W, f = 900 MHz)	η	50	57	_	%
Load Mismatch Stress (V <sub>CC</sub> = 24 Vdc, P <sub>in</sub> = 0.63 W, f = 900 MHz, VSWR = 20:1, all phase angles)	Ψ	No Degradation in Output Power			



C1 — 39 pF, 100 Mil Chip Capacitor

C2, C8, C15 — 0.8–8.0 pF Johansen Gigatrim

C3, C4 — 12 pF, Mini–Unelco

C5, C13 — 1000 pF, 350 V Unelco

C6, C14 — 10  $\mu$ F, 25 V Tantalum

C7, C11, C12 — 91 pF, Mini-Unelco

C9 — 5.0 pF, MIni-Unelco

C10 - 47 pF, 100 Mil Chip Capacitor

L1, L6 — 10 Turns #20 AWG Around 10 Ohm 1/2 Watt Resistor

L2, L5 — Ferrite Bead

L3 — 4 Turns #16 AWG Choke

L4 - 0.5", #18 AWG Wire

T1, T4 — 50 Ohm Microstrip Line

T2 — W = 165 Mils,  $\ell$  = 1946 Mils

T3 — W = 166 Mils,  $\ell$  = 1563 Mils

PC Board — 0.031" Glass Teflon ( $\epsilon_r = 2.56$ )

Figure 1. Broadband Test Fixture

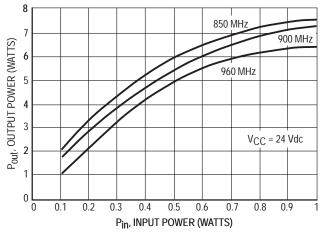


Figure 2. Output Power versus Input Power

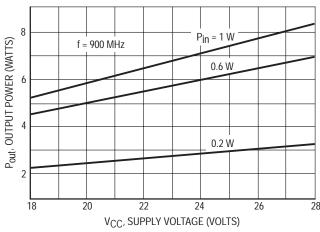


Figure 3. Output Power versus Supply Voltage

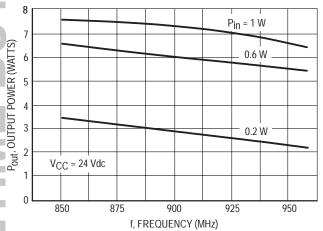


Figure 4. Output Power versus Frequency

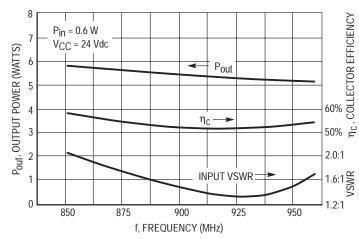


Figure 5. Typical Broadband Circuit Performance

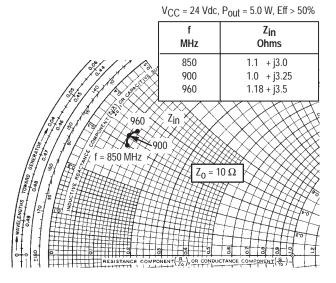


Figure 6. Series Equivalent Input Impedance

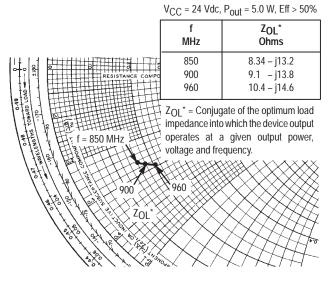
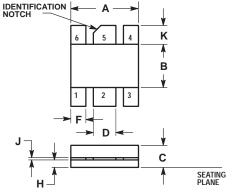


Figure 7. Series Equivalent Output Impedance

MOTOROLA RF DEVICE DATA **MRF891S** 



#### NOTES

- DIMENSIONING AND TOLERANCING PER ANSI
- Y14 5M 1982
- 2. CONTROLLING DIMENSION: INCH.

	INC	HES	MILLIMETERS		
DIM	MIN	MAX	MIN	MAX	
Α	0.355	0.365	9.02	9.27	
В	0.225	0.235	5.72	5.96	
С	0.110	0.125	2.80	3.17	
D	0.115	0.125	2.93	3.17	
F	0.075	0.085	1.91	2.15	
Н	0.035	0.045	0.89	1.14	
J	0.004	0.006	0.11	0.15	
K	0.090	0.110	2.29	2.79	

STYLE 2:

- PIN 1. EMITTER
- 2. BASE 3. EMITTER

  - EMITTER 5. COLLECTOR
  - 6. EMITTER

CASE 319A-02 **ISSUE B** 

Motorola reserves the right to make changes without further notice to any products herein. Motorola makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does Motorola assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation consequential or incidental damages. "Typical" parameters which may be provided in Motorola data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. Motorola does not convey any license under its patent rights nor the rights of others. Motorola products are not designed, intended, or authorized for use as components in systems intended for surgical implant into the body, or other applications intended to support or sustain life, or for any other application in which the failure of the Motorola product could create a situation where personal injury or death may occur. Should Buyer purchase or use Motorola products for any such unintended or unauthorized application, Buyer shall indemnify and hold Motorola and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that Motorola was negligent regarding the design or manufacture of the part. Motorola and (M) are registered trademarks of Motorola, Inc. Motorola, Inc. is an Equal Opportunity/Affirmative Action Employer.

Mfax is a trademark of Motorola. Inc.

#### How to reach us:

USA/EUROPE/Locations Not Listed: Motorola Literature Distribution; P.O. Box 5405, Denver, Colorado 80217. 1-303-675-2140 or 1-800-441-2447

JAPAN: Nippon Motorola Ltd.; SPD, Strategic Planning Office, 141, 4-32-1 Nishi-Gotanda, Shinagawa-ku, Tokyo, Japan. 81-3-5487-8488

Customer Focus Center: 1-800-521-6274

Mfax™: RMFAX0@email.sps.mot.com - TOUCHTONE 1-602-244-6609 - US & Canada ONLY 1-800-774-1848 Motorola Fax Back System - http://sps.motorola.com/mfax/

 $\Diamond$ 

ASIA/PACIFIC: Motorola Semiconductors H.K. Ltd.; 8B Tai Ping Industrial Park, 51 Ting Kok Road, Tai Po, N.T., Hong Kong. 852–26629298

HOME PAGE: http://motorola.com/sps/



MRF891S/D